Docket No.: 21854-00051-US1

(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:

Barry H. Harrison et al.

Application No.: 10/526,382 Confirmation No.: 3838

Filed: March 3, 2005 Art Unit: 2827

For: MEMORY CELL Examiner: Lam, David

RESPONSE TO RESTRICTION REQUIREMENT

MS Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

In response to the restriction requirement set forth in the Office Action mailed November 20, 2006, Applicant hereby provisionally elects **Group I**, claims 1-11, 13-14, 17-19 and 21-23, drawn to volatile/nonvolatile random access memory charging, sensing technique, directed toward **Species III**, readable on claims 4-10, 13, 21, drawn to dynamic nonvolatile random access memory with information is read by sensing resistance, for continued examination.

Applicant believes no fee is due with this response. However, if a fee is due, please charge our Deposit Account No. 22-0185, under Order No. 21854-00051-US1 from which the undersigned is authorized to draw.

Dated: December 13, 2006 Respectfully submitted,

By /Morris Liss/
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